

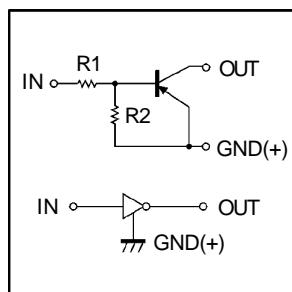
Digital transistors (built-in resistors)

- Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- 2) The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
- 3) Only the on/off conditions need to be set for operation, making device design easy.
- 4) Higher mounting densities can be achieved.

DTA115EKA

- Circuit schematic



EIAJ: SC—59

- Absolute maximum ratings($T_a=25^{\circ}\text{C}$)

Parameter		symbol	Limits		unit
Supply voltage		V_{cc}	—50		V
Input voltage		V_{IN}	-40~+10		V
Output current		I_o	-20	mA	
		$I_{C(\text{Max.})}$	-100		
Power dissipation	DTA115EE	P_d	150	mW	
	DTA115EUA/DTA115EKA		200		
	DTA115ESA		300		
Junction temperature		T_j	150		°C
Storage temperature		T_{stg}	-55~+150		°C

- Electrical characteristics($T_a=25^{\circ}\text{C}$)

Parameter	symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(\text{off})}$	—	—	-0.5	V	$V_{cc}=-5\text{V}$, $I_o=-100\mu\text{A}$
	$V_{I(\text{on})}$	-3	—	—		$V_o=-0.3\text{V}$, $I_o=-1\text{mA}$
Output Voltage	$V_{O(\text{on})}$	—	-0.1	-0.3	V	$I_o/I_i=-5\text{mA}/-0.25\text{mA}$
Input current	I_i	—	—	-0.15	mA	$V_i=-5\text{V}$
Output current	$I_{O(\text{off})}$	—	—	-0.5	μA	$V_{cc}=-50\text{V}$, $V_i=0\text{V}$
DC current gain	G_i	82	—	—	—	$V_o=-5\text{V}$, $I_o=-5\text{mA}$
Input resistance	R_i	70	100	130	KΩ	—
Resistance ratio	R_2 / R_1	0.8	1	1.2	—	—
Transition frequency	f_T	—	250	—	MHz	$V_{ce}=10\text{V}$, $I_E=5\text{mA}$, $f=100\text{MHz}^*$

*Transition frequency of the device